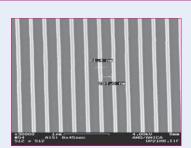
micro resist technology GmbH Köpenicker Straße 325 12555 Berlin-Köpenick Germany Telephone +49 30 65762192 Fax +49 30 65762193 E-Mail mrt@microresist.de www.microresist.com



# **UV-curable polymers for UV-based nanoimprint lithography**

#### mr-UVCur21 and mr-UVCur06 – fast curing polymer systems for pattern transfer



80 nm lines imprinted in mr-UVCur21, pattern depth 110 nm (Courtesy of AMO)

1000 0000 1m

Excellent filling of mould patterns with demanding filling factors, 100x100  $\mu m^2$  squares, mr-UVCur21 (Courtesy of AMO)



Imprinted lines, sub-30 nm resolution (Courtesy of AMO)



800 nm squares, 1200 nm pitch, imprinted in mr-UVCur06, large-area imprint (Courtesy of Profactor)

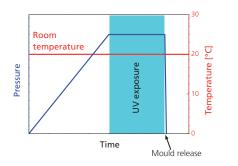


350 nm trenches, mr-UVCur06, residual layer thickness < 10 nm (Courtesy of Profactor)

k 02 09 19 0

#### Attributes

- <sup>–</sup> Compatibility with various nanoimprint tools:
- <sup>-</sup> Wafer-scale or step&repeat UV-imprints
- <sup>-</sup> Imprinting in vacuum or under atmospheric pressure
- <sup>–</sup> Excellent film quality and thickness uniformity
- Short cycle times due to fast filling of mould cavities
- Pattern resolution below 30 nm (mr-UVCur21, limited by the mould, not by the polymer)
- <sup>-</sup> Very low residual layer thickness (< 10 nm)
- Short curing times, low UV doses, compatibility with various UV lamps and filter systems
- High plasma etch resistance, no residues after oxygen plasma etching (silicon-free polymer)
- <sup>–</sup> Appropriate adhesion promoter available



## **Technical Data**

UV-curable Polymer	mr-UVCur06	mr-UVCur21	mr-UVCur21SF	
Coating method	Spin coating	Spin coating	Dispensing, spin coating	
Process conditions	Imprint: room temperature process, low imprint pressures (>100 mbar), imprint in vacuum or under atmospheric pressure UV exposure: broad band or i-line, curing time few seconds			
Smallest feature size Aspect ratio	50 nm < 2	< 30 nm > 2	< 30 nm > 2	
Ready-to-use solutions for various film thick- nesses * (3000 rpm)	240 nm	100nm 200nm 300nm	1.6 µm (spin coating)	
Diluents	mr-T 1070	mr-T 1070	mr-T 1070	
Adhesion Promoter	mr-APS1	mr-APS1	mr-APS1	

#### \* Different film thicknesses are available on request for mr-UVCur21

# Applications

- Etch mask for pattern transfer processes (dry and wet etching)
- <sup>–</sup> Fabrication of nanopatterns
  - <sup>-</sup> Data storage
  - Nano-optical devices,
  - sub-wavelength optical elements
  - <sup>–</sup> Photonic crystals
  - <sup>-</sup> Micro- and Nanofluidics
  - <sup>-</sup> Microelectronics
- <sup>–</sup> Coating of various substrate materials, e.g. Si, SiO<sub>2</sub>, Al

### **Process Flow**

